

# isc N-Channel MOSFET Transistor

## IRFB7540, IIRFB7540

## FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on) ≤5.1mΩ
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

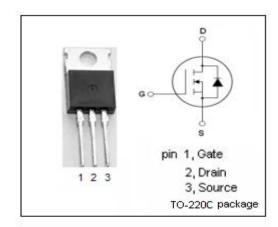
• reliable device for use in a wide variety of applications

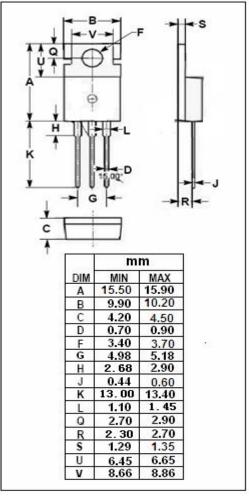
## • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	60	V				
V <sub>GS</sub>	Gate-Source Voltage	±20	V				
I <sub>D</sub>	Drain Current-Continuous	80	А				
I <sub>DM</sub>	Drain Current-Single Pulsed	380	А				
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	160	W				
Tj	Max. Operating Junction Temperature	175	$^{\circ}$ C				
T <sub>stg</sub>	Storage Temperature	-55~175	$^{\circ}$				

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.21	°C/W
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W







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## **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	60			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =250 μ A	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =55A			5.1	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V			±0.1	μ <b>A</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =60V; V <sub>GS</sub> = 0V			1.0	μ <b>А</b>
V <sub>SD</sub>	Diode forward voltage	Is=55A, V <sub>GS</sub> = 0 V			1.2	V

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